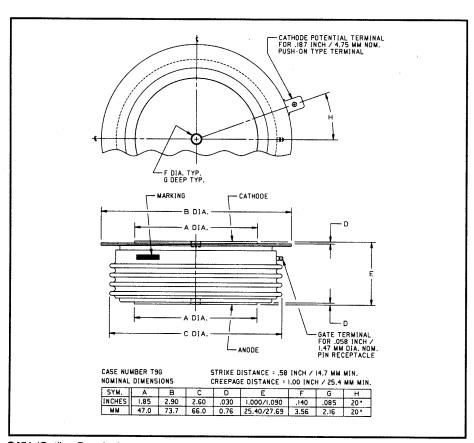


## Phase Control SCR 1500 Amperes Average 2400 Volts

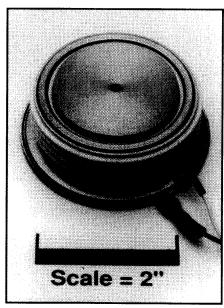


C451 (Outline Drawing)

## Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C451LD is a 2400 Volt, 1500 Ampere Phase Control SCR.

|      | Volt                                 | Current |                    |
|------|--------------------------------------|---------|--------------------|
| Туре | V <sub>DRM</sub><br>V <sub>RRM</sub> | Code    | l <sub>T(av)</sub> |
| C451 | 1400                                 | PD      | 1500               |
|      | 1600                                 | РМ      |                    |
| •    | 1800                                 | PN      |                    |
|      | 2000                                 | L       |                    |
|      | 2200                                 | LB      |                    |
|      | 2400                                 | LD      |                    |



**C451 Phase Control SCR** 1500 Amperes Average, 2400 Volts

### **Description:**

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

#### Features:

- ☐ Low On-State Voltage
- ☐ High di/dt Capability
- ☐ High dv/dt Capability☐ Hermetic Packaging
- Excellent Surge and I<sup>2</sup>t Ratings

## **Applications:**

- Power Supplies
- VAR Generators



C451 Phase Control SCR 1500 Amperes Average, 2400 Volts

## **Absolute Maximum Ratings**

| Characteristics   | Symbol              | C451                    | Units<br>Volts     |  |
|---|---------------------|-------------------------|--------------------|--|
| Non-repetitive Transient Peak Reverse Voltage               | V <sub>RSM</sub>    | V <sub>RRM</sub> + 100V |                    |  |
| RMS On-state Current, T <sub>C</sub> = 64°C                 | I <sub>T(rms)</sub> | 2350                    | Amperes            |  |
| Average Current 180° Sine Wave, T <sub>C</sub> = 64°C       | I <sub>T(av)</sub>  | 1500                    | Amperes            |  |
| RMS On-state Current, T <sub>C</sub> = 55°C                 | lT(rms)             | 2590                    | Amperes            |  |
| Average Current 180° Sine Wave, T <sub>C</sub> = 55°C       | I <sub>T(av)</sub>  | 1650                    | Amperes            |  |
| Peak One Cycle Surge On-state Current (Non-repetitive) 60Hz | l <sub>tsm</sub>    | 23000                   | Amperes            |  |
| Peak One Cycle Surge On-state Current (Non-repetitive) 50Hz | I <sub>tsm</sub>    | 20800                   | Amperes            |  |
| Critical Rate-of-rise of On-state Current (Non-repetitive)  | di/dt               | 400                     | A/μsec             |  |
| Critical Rate-of-rise of On-state Current (Repetitive)      | di/dt               | 75                      | A/μsec             |  |
| I <sup>2</sup> t (for Fusing) for One Cycle, 60Hz           | ı <sup>2</sup> t    | 2.2 x 10 <sup>6</sup>   | A <sup>2</sup> sec |  |
| Peak Gate Power Dissipation                                 | PGM                 | 200                     | Watts              |  |
| Average Gate Power Dissipation                              | P <sub>G(av)</sub>  | 5                       | Watts              |  |
| Operating Temperature                                       | T <sub>i</sub>      | -40 to +125°C           | °C                 |  |
| Storage Temperature   | T <sub>stg</sub>    | -40 to +150°C           | °C                 |  |
| Approximate Weight  |                     | 1                       | lb.                |  |
|   |                     | 454                     | g                  |  |
| Mounting Force  |                     | 5500 to 6000            | lb.                |  |
|   |                     | 2450 to 2670            | kg.                |  |



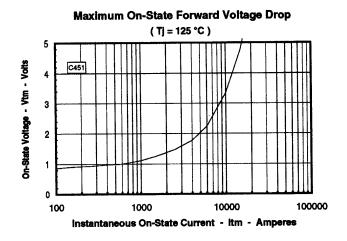
C451
Phase Control SCR
1500 Amperes Average, 2400 Volts

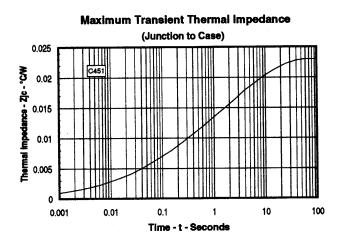
# Electrical Characteristics, $T_j = 25^{\circ}C$ Unless Otherwise Specified

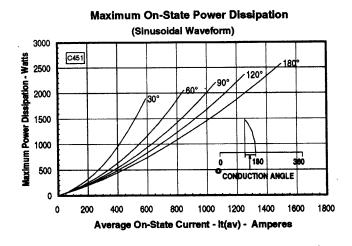
| Characteristics                              | Symbol              | Test Conditions  | Min.                                  | Тур. | Max.                  | Units        |
|--|---------------------|--|---------------------------------------|------|-----------------------|--------------|
| Repetitive Peak Reverse Leakage Current      | IRRM                | T <sub>i</sub> = 125°C, V <sub>R</sub> = V <sub>RRM</sub>          | ·                                     |      | 45                    | mA           |
| Repetitive Peak Forward Leakage Current      | IDRM                | T <sub>j</sub> = 125°C, V <sub>D</sub> = V <sub>DRM</sub>          |                                       |      | 45                    | mA           |
| Peak On-state Voltage                        | V <sub>TM</sub>     | I <sub>TM</sub> = 3000A Peak                                       |                                       |      | 1.7                   | Volts        |
|  |                     | Duty Cycle < 0.1%  |                                       |      | •••                   | 70.10        |
| Threshold Voltage, Low-level                 | V <sub>(TO)1</sub>  | $T_j = 125^{\circ}C$ , $I = 15\%$ , $I_{T(av)}$ to $\pi I_{T(av)}$ |                                       |      | 0.87956               | Volts        |
| Slope Resistance, Low-level                  | r <sub>T1</sub>     | ) (av)   |                                       |      | 0.2271                | mΩ           |
| Threshold Voltage, High-level                | V <sub>(TO)2</sub>  | $T_j = 125$ °C, $I = \pi I_{T(av)}$ to $I_{TSM}$                   |                                       |      | 0.59931               | Volts        |
| Slope Resistance, High-level                 | rT2                 |  |                                       |      | 0.2781                | mΩ           |
| V <sub>TM</sub> Coefficients, Low-level      |                     | $T_j = 125^{\circ}C$ , $I = 15\% I_{T(av)} to \pi I_{T(av)}$       |                                       |      |                       |              |
|  |                     | , (2.,   |                                       | A    | 1 = 0.839             | 82           |
|  |                     |  |                                       | В    | 1 = 4.972             | E-04         |
|  |                     |  |                                       | С    | 1 = 2.032             | E-04         |
| V O-W-1-1-1-1                                |                     |  |                                       | D    | 1 = 0.002             | 154          |
| V <sub>TM</sub> Coefficients, High-level     |                     | $T_j = 125$ °C, $I = \pi I_{T(av)}$ to $I_{TSM}$                   |                                       |      |                       |              |
|  |                     |  |                                       |      | <sub>2</sub> = 12.127 |              |
|  |                     |  |                                       |      | 2 = -1.809            |              |
|  |                     |  |                                       |      | 2 = 1.429             |              |
| Torical Data T                               |                     |  | · · · · · · · · · · · · · · · · · · · | D    | 2 = 0.064             | 436          |
| Typical Delay Time                           | <sup>t</sup> d      | $I_T = 50A$ , Gate = 20V, $20\Omega$ ,                             |                                       | 0.7  |                       | μsec         |
| Typical Turn-off Time                        | •                   | 0.1μsec Rise<br>T <sub>i</sub> = 125°C, I <sub>T</sub> = 2000A,    |                                       | 450  |                       |              |
| 7,   | <sup>t</sup> q      | $di_{R}/dt = 25A/\mu sec Reapplied$                                |                                       | 150  |                       | μsec         |
|  |                     | dv/dt = 200V/μsec Linear to  |                                       |      |                       |              |
|  |                     | $80\% V_{DRM}, V_{R} = 50V,$                                       |                                       |      |                       |              |
|  |                     | Gate = 0V, $R_{GK} = 100\Omega$                                    |                                       |      |                       |              |
| Minimum Critical dv/dt - Exponential to VDRM | dv/dt               | T <sub>i</sub> = 125°C   | 400                                   |      |                       | Wusaa        |
| Gate Trigger Current                         | <sup>I</sup> GT     | T <sub>i</sub> = 25°C,   |                                       |      | 200                   | V/μsec<br>mA |
|  | G1                  | $V_D = 20V_{DC}$ , $R_L = 3\Omega$                                 |                                       |      | 200                   | ША           |
| Gate Trigger Voltage                         | V <sub>GT</sub>     | $T_i = -40^{\circ}\text{C to } +125^{\circ}\text{C},$              |                                       |      | 5.0                   | Volts        |
| •  | ·Gi                 | $V_D = 20V$ , $R_L = 3\Omega$                                      |                                       |      | 5.0                   | VOILS        |
| Non-Triggering Gate Voltage                  | V <sub>GDM</sub>    | $T_i = 125^{\circ}C,$  | <del></del>                           |      | 0.45                  | 14-11-       |
| 50, and contage                              | GDM                 | ,  |                                       |      | 0.15                  | Volts        |
| Peak Forward Gate Current                    | loma                | $V_D = V_{DRM}, R_L = 1000\Omega$                                  |                                       |      | 40                    |              |
| Peak Reverse Gate Voltage                    | IGTM                |  |                                       |      | . 10                  | Α            |
| - Jan 11070130 Gate Foliage                  | VGRM                | <del></del>  |                                       |      | 5                     | Volts        |
| Thermal Characteristics                      |                     |  |                                       |      |                       |              |
| Maximum Thermal Resistance, Double Sided Co  | oling               |  |                                       |      |                       |              |
| Junction-to-Case                             | $R_{\theta(j-c)}$   |  |                                       |      | 0.025                 | °C/W         |
| Case-to-Sink                                 |                     |  |                                       |      |                       |              |
|  | R <sub>θ(c-s)</sub> |  |                                       |      | 0.0075                | °C/W         |

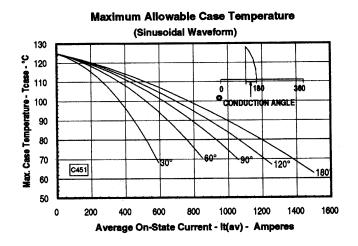


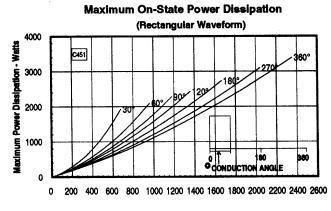
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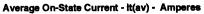


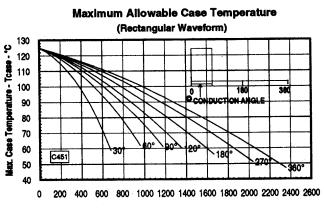












Average On-State Current - It(av) - Amperes